

LM2901

Low power quad voltage comparator

Features

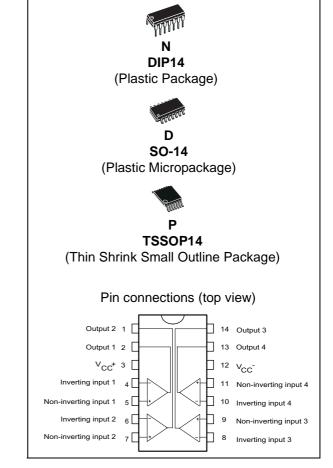
- Wide single supply voltage range or dual supplies for all devices: +2V to +36V or ±1V to ±18V
- Very low supply current (1.1mA) independent of supply voltage (1.4mW/comparator at +5V)
- Low input bias current: 25nA typ.
- Low input offset current: ±5nA typ.
- Input common-mode voltage range includes ground
- Low output saturation voltage: 250mV typ. (I_O = 4mA)
- Differential input voltage range equal to the supply voltage
- TTL, DTL, ECL, MOS, CMOS compatible outputs

Description

This device consists of four independent precision voltage comparators. All these comparators are designed specifically to operate from a single supply over a wide range of voltages. Operation from split power supplies is also possible.

These comparators also have a unique characteristic in that the input common-mode voltage range includes ground even though operated from a single power supply voltage.

Order codes



Part number	Temperature range	Package	Packing	Marking
LM2901N		DIP14	Tube	LM2901N
LM2901D/LM2901DT		SO-14	Tube or tape & reel	
LM2901PT	-40°C, +125°C	TSSOP14 (Thin shrink outline package)	Tape & reel	2901
LM2901YD/YDT		SO-14 (automotive grade level)	Tube or tape & reel	2901Y
LM2901YPT		TSSOP14 (automotive grade level)	Tape & reel	20011

July 2006

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1 Absolute maximum ratings and operating conditions

Table 1.	Absolute	maximum	ratings
	/ 10001410	maximam	laungo

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	±18 to 36	V
V _{ID}	Differential input voltage	±36	V
VI	Input voltage	-0.3 to +36	V
	Output short-circuit to ground ⁽¹⁾		
P _d	Power dissipation ⁽²⁾ DIP14 SO-14 TSSOP14	1500 830 710	mW
Τ _J	Junction temperature	+150	°C
T _{stg}	Storage temperature range	-65 to +150	°C
	HBM: human body model ⁽³⁾	500	V
ESD	MM: machine model ⁽⁴⁾	100	V
	CDM: charged device model	1500	V

1. Short-circuit from the output to V_{CC}^+ can cause excessive heating and eventual destruction. The maximum output current is approximately 20mA, independent of the magnitude of V_{CC}^+ .

2. Pd is calculated with $T_{amb} = +25^{\circ}$ C, $T_j = +150^{\circ}$ C and $R_{thja} = 80^{\circ}$ C/W for DIP14 package, $R_{thja} = 150^{\circ}$ C/W for SO-14 package, $R_{thja} = 175^{\circ}$ C/W for TSSOP14 package.

3. Human body model, 100pF discharged through a $1.5k\Omega$ resistor into pin of device.

4. Machine model ESD, a 200pF cap is charged to the specified voltage, then discharged directly into the IC with no external series resistor (internal resistor < 5Ω), into pin to pin of device.

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	2 to 32 ±1 to ±16	V
V _{icm}	Common mode input voltage range	0 to (V _{CC} ⁺ -1.5)	V
T _{oper}	Operating free-air temperature range	-40 to +125	°C

2 Schematic diagram

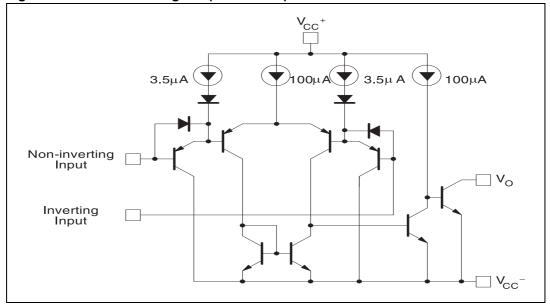


Figure 1. Schematic diagram (1/4 LM2901)



3 Electrical characteristics

Table 3.	Electrical characteristics at $V_{CC}^+ = 5V$, $V_{cc}^- = GND$, $T_{amb} = 25^{\circ}C$
	(unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Unit
V _{io}	Input offset voltage ⁽¹⁾ $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		1	7 15	mV
I _{io}	Input offset current $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		5	50 150	nA
I _{ib}	Input bias current $(I_1^+ \text{ or } I_1^-)^{(2)}$ $T_{amb} = 2.5V$ $T_{min} \le T_{amb} \le T_{max}$		25	250 400	nA
A _{vd}	Large signal voltage gain (V _{cc} = 15V,R _L =15kΩ, V _o =1 to 11V)	25	200		V/mV
I _{cc}	Supply current (all comparators) $V_{CC} = +5V$, no load $V_{CC} = +30V$, no load		1.1 1.3	2 2.5	mA
V _{icm}	Input common mode voltage range $(V_{cc}=30V)^{(3)}$ $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	0 0		V _{CC} ⁺ -1.5 V _{CC} ⁺ -2	V
V _{id}	Differential input voltage ⁽⁴⁾			V _{CC} ⁺	V
V _{OL}	Low level output voltage $V_{id} = -1V$, $I_{sink} = 4mA$ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		250	400 700	mV
I _{oh}	$ High level output current \\ (V_{CC} = V_o = 30V, V_{id} = 1V) \\ T_{amb} = +25^{\circ}C \\ T_{min} \leq T_{amb} \leq T_{max} $		0.1	1	nA μA
I _{sink}	Output sink current ($V_{id} = -1V, V_o = 1.5V$)	6	16		mA
t _{re}	Small signal response time ⁽⁵⁾ ($R_L = 5.1 k\Omega$ connected to V_{CC}^+)		1.3		μs
t _{rel}	Large signal response time ⁽⁶⁾ TTL input ($V_{ref} = +1.4 \text{ V}, R_L=5.1 \text{k}\Omega$ to V_{CC}^+) Output signal at 50% of final value Output signal at 95% of final value			500 1	ns μs

1. At output switch point, $V_0 \approx 1.4V$, $R_s = 0$ with V_{CC}^+ from 5V to 30V, and over the full input common-mode range (0V to V_{CC}^+ –1.5V).

2. The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output, so no loading charge exists on the reference of input lines.



- 3. The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is V_{CC}^+ –1.5V, but either or both inputs can go to +30V without damage.
- 4. The response time specified is for a 100mV input step with 5mV overdrive.
- 5. Positive excursions of input voltage may exceed the power supply level. As long as the other voltage remains within the common-mode range, the comparator will provide a proper output state. The low input voltage state must not be less than -0.3V (or 0.3V below the negative power supply, if used).
- 6. Maximum values are guaranteed by design.

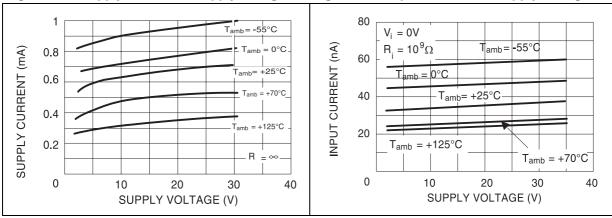
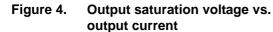


Figure 2. Supply current vs. supply voltage Figure 3. Input current vs. supply voltage



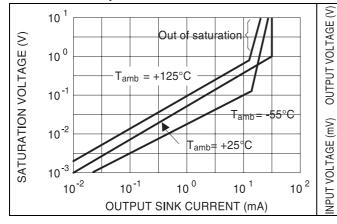


Figure 6. Response time for various input overdrives - positive transition

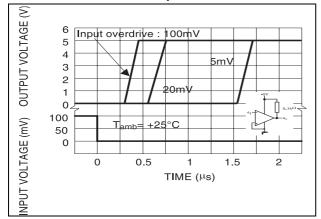
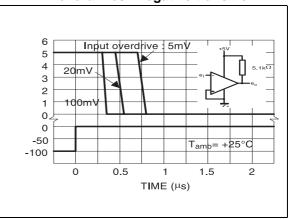


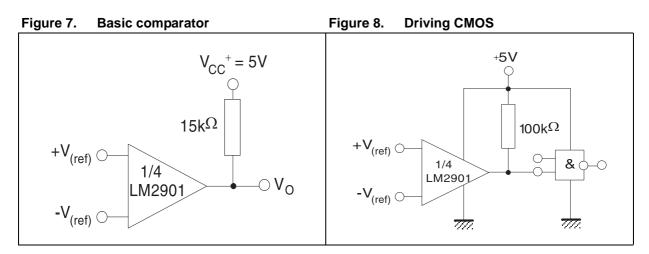
Figure 5. Response time for various input overdrives - negative transition





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Typical applications schematics





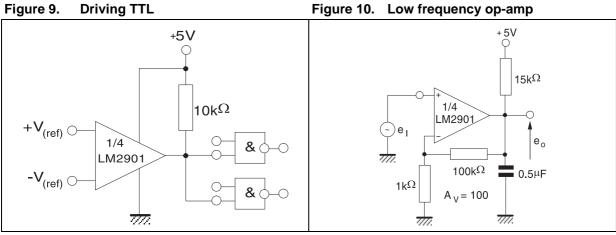




Figure 12. Transducer amplifier

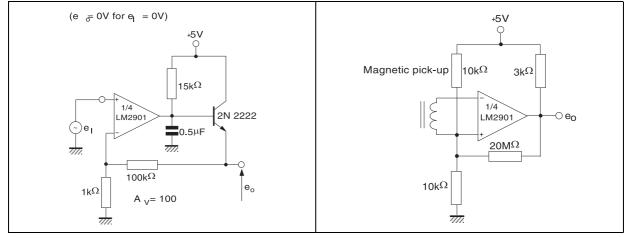
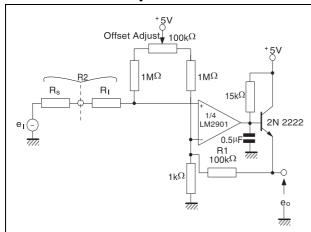
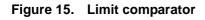
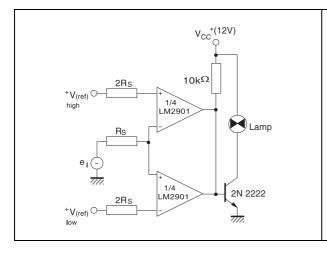


Figure 13. Low frequency op- amp with offset adjust









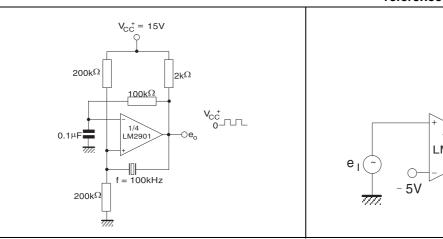
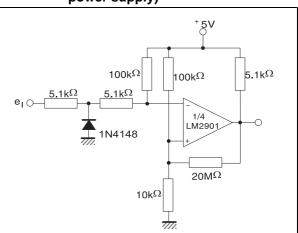
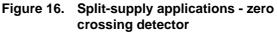
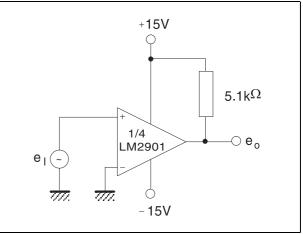
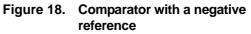


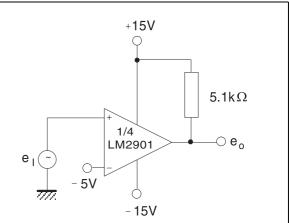
Figure 14. Zero crossing detector (single power supply)











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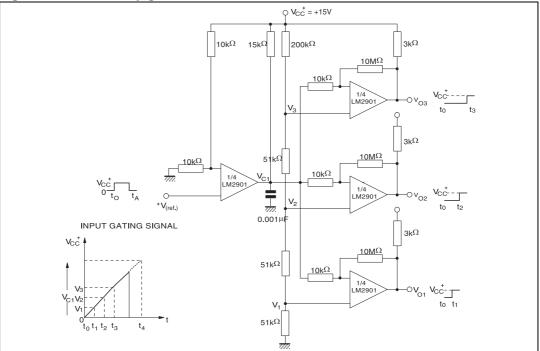
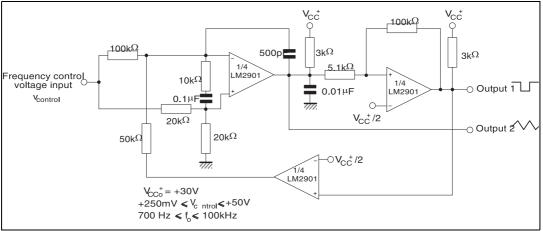


Figure 19. Time delay generator







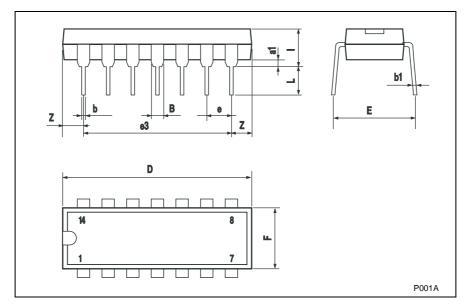
4 Package mechanical data

In order to meet environmental requirements, STMicroelectronics offers these devices in ECOPACK[®] packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an STMicroelectronics trademark. ECOPACK specifications are available at: <u>www.st.com</u>.



4.1 DIP14 package

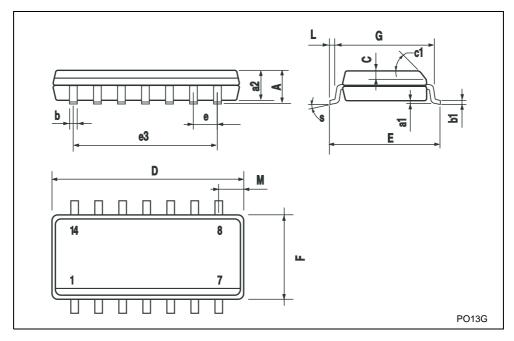
	Plastic DIP-14 MECHANICAL DATA						
DIM		mm.			inch		
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
a1	0.51			0.020			
В	1.39		1.65	0.055		0.065	
b		0.5			0.020		
b1		0.25			0.010		
D			20			0.787	
Е		8.5			0.335		
е		2.54			0.100		
e3		15.24			0.600		
F			7.1			0.280	
I			5.1			0.201	
L		3.3			0.130		
Z	1.27		2.54	0.050		0.100	





4.2 SO-14 package

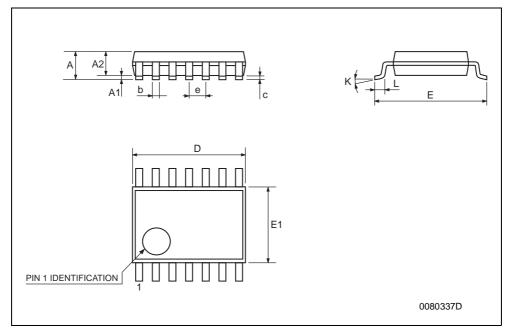
	SO-14 MECHANICAL DATA					
DIM.		mm.			inch	
	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
А			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
С		0.5			0.019	
c1			45°	(typ.)	•	•
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
е		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
М			0.68			0.026
S	8° (max.)					





4.3 TSSOP14 package

	TSSOP14 MECHANICAL DATA					
DIM		mm.			inch	
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
А			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
с	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
е		0.65 BSC			0.0256 BSC	
к	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030





5 Revision history

Table 4.	Document	revision	history
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Date	Revision	Changes
Jan-2002	1	Initial release.
Jul-2005	2	 PPAP references inserted in the datasheet see <i>Table : Order codes on page 1</i>. ESD protection inserted in <i>Table 1 on page 3</i>.
Oct-2005	3	 The following changes were made in this revision: PPAP part number added in table Order codes on page 1. Formatting changes throughout.
18-Jul-2006	4	ESD HBM value corrected in Table 1 on page 3.



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